

## PROTECTION PRODUCTS

### Description

RailClamps are surge rated diode arrays designed to protect high speed data interfaces. The SR series has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by electrostatic discharge (**ESD**), electrical fast transients (**EFT**), and **lightning**.

The unique design of the SRDA series devices incorporates surge rated, low capacitance steering diodes and a TVS diode in a single package. During transient conditions, the steering diodes direct the transient to either the positive side of the power supply line or to ground. The internal TVS diode prevents over-voltage on the power line, protecting any downstream components.

The low capacitance array configuration allows the user to protect two high-speed data or transmission lines. The low inductance construction minimizes voltage overshoot during high current surges.

### Features

- ◆ Transient protection for high-speed data lines to **IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact)**  
**IEC 61000-4-4 (EFT) 40A (5/50ns)**  
**IEC 61000-4-5 (Lightning) 24A (8/20µs)**
- ◆ Array of surge rated diodes with internal TVS diode
- ◆ Protects four I/O lines and power supply line
- ◆ Low capacitance (<15pF) for high-speed interfaces
- ◆ Low operating and clamping voltages
- ◆ Solid-state technology

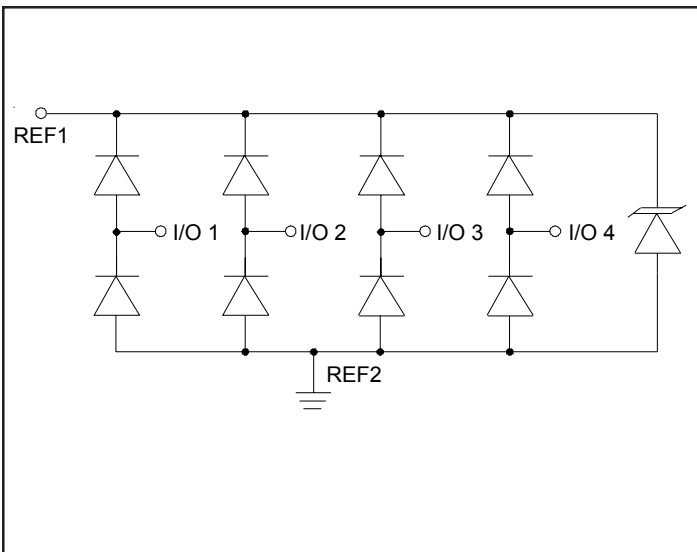
### Mechanical Characteristics

- ◆ JEDEC SO-8 package
- ◆ UL 497B listed
- ◆ Molding compound flammability rating: UL 94V-0
- ◆ Marking : Part number, date code, logo
- ◆ Packaging : Tube or Tape and Reel per EIA 481

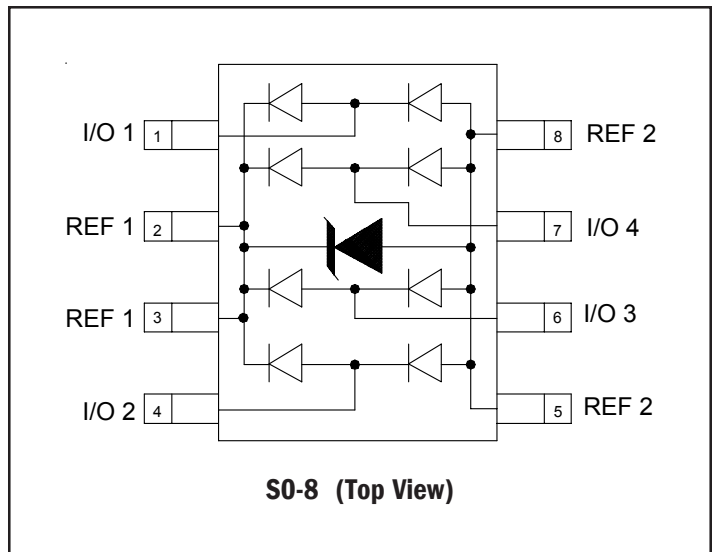
### Applications

- ◆ USB Power and Data Line Protection
- ◆ T1/E1 secondary IC Side Protection
- ◆ T3/E3 secondary IC Side Protection
- ◆ HDSL, SDSL secondary IC Side Protection
- ◆ Video Line Protection
- ◆ Microcontroller Input Protection
- ◆ Base stations
- ◆ I<sup>2</sup>C Bus Protection

### Circuit Diagram



### Schematic and PIN Configuration



**PROTECTION PRODUCTS**
**Absolute Maximum Rating**

Rating	Symbol	Value	Units
Peak Pulse Power ( $t_p = 8/20\mu s$ )	$P_{pk}$	500	Watts
Peak Forward Voltage ( $I_F = 1A, t_p = 8/20\mu s$ )	$V_{FP}$	1.5	V
Lead Soldering Temperature	$T_L$	260 (10 sec.)	°C
Operating Temperature	$T_J$	-55 to +125	°C
Storage Temperature	$T_{STG}$	-55 to +150	°C

**Electrical Characteristics**

SRDA3.3-4 <sup>1</sup>						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	$V_{RWM}$				3.3	V
Punch-Through Voltage	$V_{PT}$	$I_{PT} = 2\mu A$	3.5			V
Snap-Back Voltage	$V_{SB}$	$I_{SB} = 50mA$	2.8			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 3.3V, T=25^\circ C$			1	$\mu A$
Clamping Voltage	$V_C$	$I_{PP} = 1A, t_p = 8/20\mu s$			5.3	V
Clamping Voltage	$V_C$	$I_{PP} = 10A, t_p = 8/20\mu s$			10	V
Clamping Voltage	$V_C$	$I_{PP} = 25A, t_p = 8/20\mu s$			15	V
Peak Pulse Current	$I_{PP}$	$t_p = 8/20\mu s$			25	A
Junction Capacitance	$C_j$	Between I/O pins and Ground $V_R = 0V, f = 1MHz$		8	15	pF
		Between I/O pins $V_R = 0V, f = 1MHz$		4		pF

**Note:**

(1) The SRDA3.3-4 is constructed using Semtech's proprietary EPD process technology. See applications section for more information.

**PROTECTION PRODUCTS**
**Electrical Characteristics (continued)**

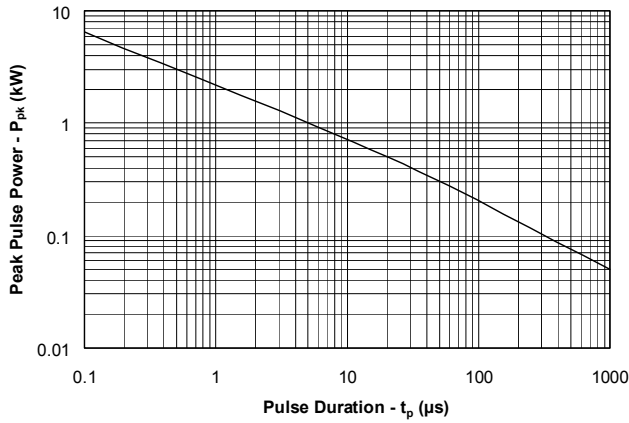
<b>SRDA05-4</b>						
<b>Parameter</b>	<b>Symbol</b>	<b>Conditions</b>	<b>Minimum</b>	<b>Typical</b>	<b>Maximum</b>	<b>Units</b>
Reverse Stand-Off Voltage	$V_{RWM}$				5	V
Reverse Breakdown Voltage	$V_{BR}$	$I_t = 1mA$	6			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 5V, T=25^{\circ}C$			10	$\mu A$
Clamping Voltage	$V_C$	$I_{PP} = 1A, t_p = 8/20\mu s$			9.8	V
Clamping Voltage	$V_C$	$I_{PP} = 10A, t_p = 8/20\mu s$			12	V
Clamping Voltage	$V_C$	$I_{PP} = 25A, t_p = 8/20\mu s$			20	V
Peak Pulse Current	$I_{PP}$	$t_p = 8/20\mu s$			25	A
Junction Capacitance	$C_j$	Between I/O pins and Ground $V_R = 0V, f = 1MHz$		8	15	pF
		Between I/O pins $V_R = 0V, f = 1MHz$		4		pF

<b>SRDA12-4</b>						
<b>Parameter</b>	<b>Symbol</b>	<b>Conditions</b>	<b>Minimum</b>	<b>Typical</b>	<b>Maximum</b>	<b>Units</b>
Reverse Stand-Off Voltage	$V_{RWM}$				12	V
Reverse Breakdown Voltage	$V_{BR}$	$I_t = 1mA$	13.3			V
Reverse Leakage Current	$I_R$	$V_{RWM} = 12V, T=25^{\circ}C$			1	$\mu A$
Clamping Voltage	$V_C$	$I_{PP} = 1A, t_p = 8/20\mu s$			17	V
Clamping Voltage	$V_C$	$I_{PP} = 10A, t_p = 8/20\mu s$			20	V
Clamping Voltage	$V_C$	$I_{PP} = 20A, t_p = 8/20\mu s$			25	V
Peak Pulse Current	$I_{PP}$	$t_p = 8/20\mu s$			20	A
Junction Capacitance	$C_j$	Between I/O pins and Ground $V_R = 0V, f = 1MHz$		8	15	pF
		Between I/O pins $V_R = 0V, f = 1MHz$		4		pF

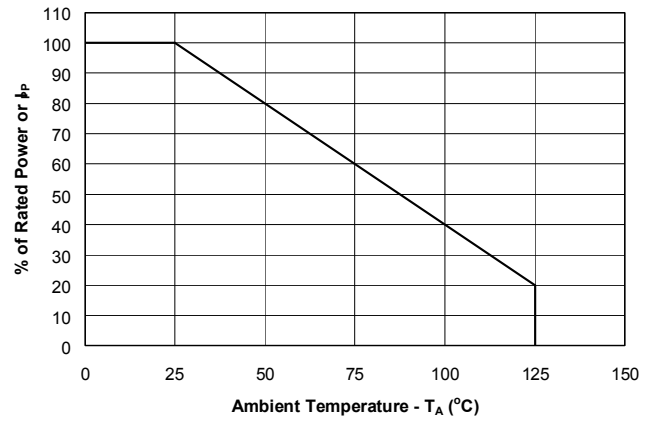
PROTECTION PRODUCTS

Typical Characteristics

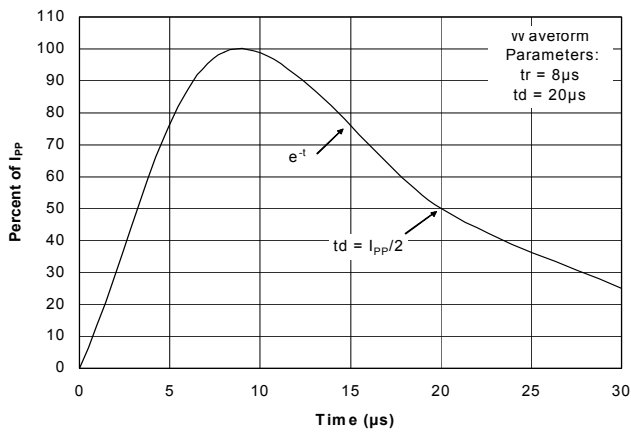
Non-Repetitive Peak Pulse Power vs. Pulse Time



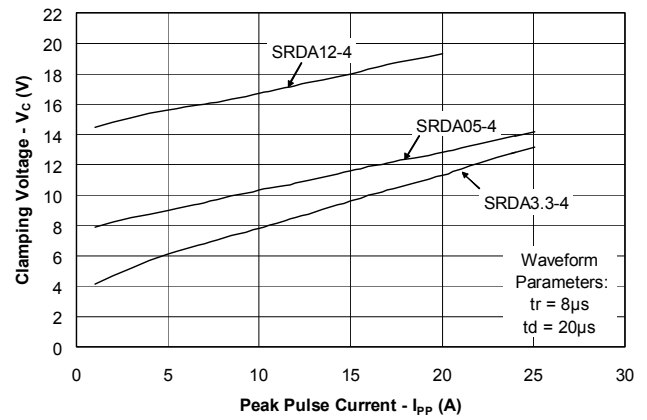
Power Derating Curve



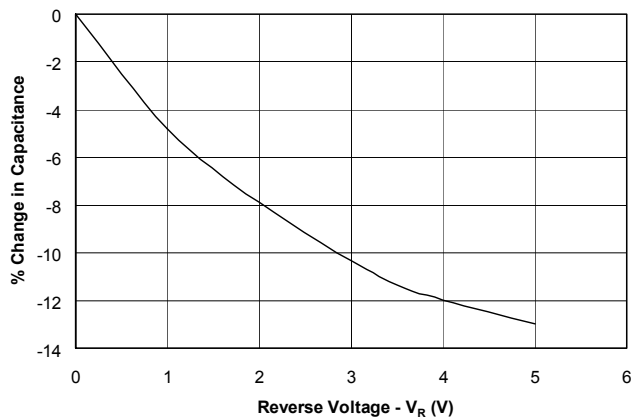
Pulse Waveform



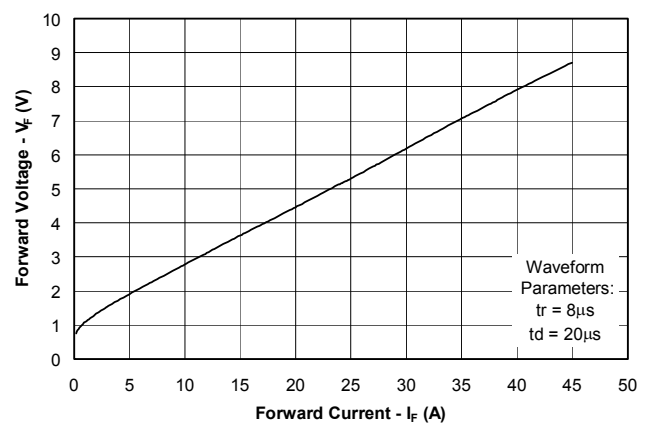
Clamping Voltage vs. Peak Pulse Current



Variation of Capacitance vs. Reverse Voltage



Forward Voltage vs. Forward Current



## PROTECTION PRODUCTS

### Applications Information

#### Device Connection Options for Protection of Four High-Speed Lines

The SRDA TVS is designed to protect four data lines from transient overvoltages by clamping them to a fixed reference. When the voltage on the protected line exceeds the reference voltage (plus diode  $V_F$ ) the steering diodes are forward biased, conducting the transient current away from the sensitive circuitry. Data lines are connected at pins 1, 4, 6 and 7. The negative reference is connected at pins 5 and 8. These pins should be connected directly to a ground plane on the board for best results. The path length is kept as short as possible to minimize parasitic inductance.

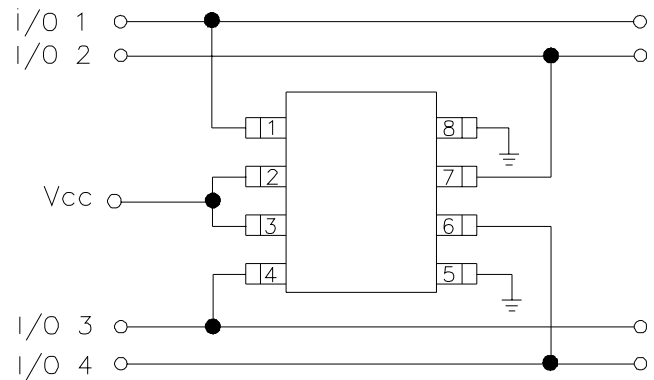
The positive reference is connected at pins 2 and 3. The options for connecting the positive reference are as follows:

1. To protect data lines and the power line, connect pins 2 & 3 directly to the positive supply rail ( $V_{CC}$ ). In this configuration the data lines are referenced to the supply voltage. The internal TVS diode prevents over-voltage on the supply rail.
2. The SRDA can be isolated from the power supply by adding a series resistor between pins 2 and 3 and  $V_{CC}$ . A value of  $10k\Omega$  is recommended. The internal TVS and steering diodes remain biased, providing the advantage of lower capacitance.
3. In applications where no positive supply reference is available, or complete supply isolation is desired, the internal TVS may be used as the reference. In this case, pins 2 and 3 are not connected. The steering diodes will begin to conduct when the voltage on the protected line exceeds the working voltage of the TVS (plus one diode drop).

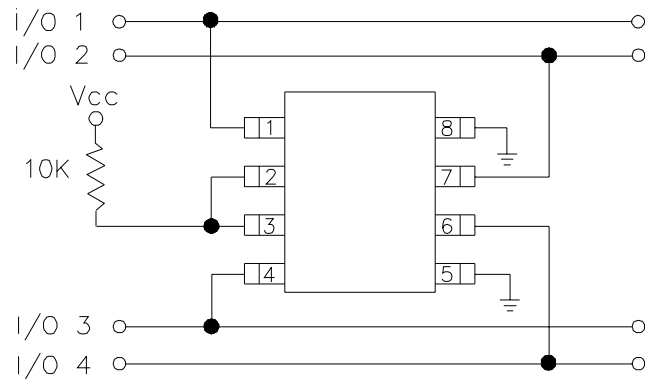
#### ESD Protection With RailClamps

RailClamps are optimized for ESD protection using the rail-to-rail topology. Along with good board layout, these devices virtually eliminate the disadvantages of using discrete components to implement this topology. Consider the situation shown in Figure 1 where discrete diodes or diode arrays are configured for rail-to-rail protection on a high speed line. During positive duration ESD events, the top diode will be forward biased when the voltage on the protected line exceeds the reference voltage plus the  $V_F$  drop of the diode. For negative events, the bottom diode will be biased when the voltage exceeds the  $V_F$  of the diode. At first

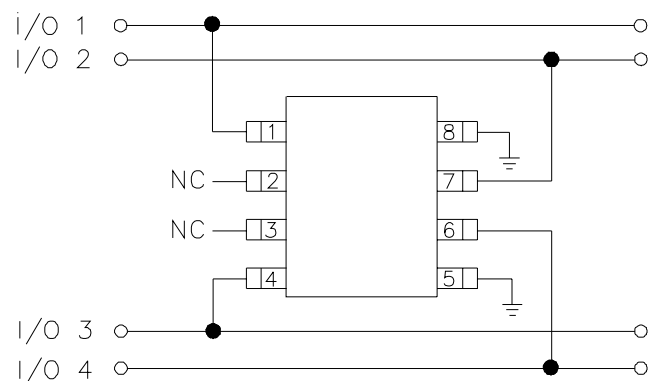
#### Data Line and Power Supply Protection Using $V_{CC}$ as reference



#### Data Line Protection with Bias and Power Supply Isolation Resistor



#### Data Line Protection Using Internal TVS Diode as Reference



**PROTECTION PRODUCTS**
**Applications Information (continued)**

approximation, the clamping voltage due to the characteristics of the protection diodes is given by:

$$V_C = V_{CC} + V_F \quad (\text{for positive duration pulses})$$

$$V_C = -V_F \quad (\text{for negative duration pulses})$$

However, for fast rise time transient events, the effects of parasitic inductance must also be considered as shown in Figure 2. Therefore, the actual clamping voltage seen by the protected circuit will be:

$$V_C = V_{CC} + V_F + L_P \frac{di_{ESD}}{dt} \quad (\text{for positive duration pulses})$$

$$V_C = -V_F - L_G \frac{di_{ESD}}{dt} \quad (\text{for negative duration pulses})$$

ESD current reaches a peak amplitude of 30A in 1ns for a level 4 ESD contact discharge per IEC 61000-4-2. Therefore, the voltage overshoot due to 1nH of series inductance is:

$$V_P = L_P \frac{di_{ESD}}{dt} = 1 \times 10^{-9} (30 / 1 \times 10^{-9}) = 30V$$

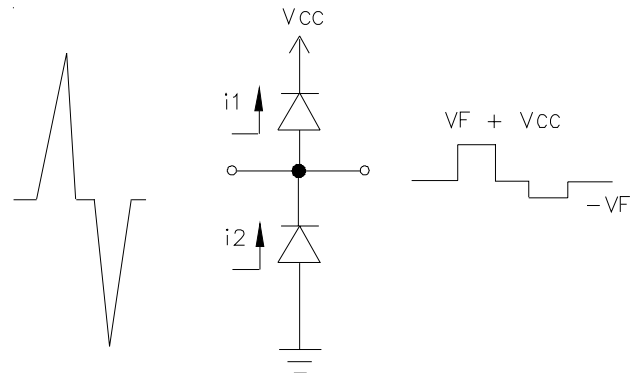
Example:

Consider a  $V_{CC} = 5V$ , a typical  $V_F$  of 30V (at 30A) for the steering diode and a series trace inductance of 10nH. The clamping voltage seen by the protected IC for a positive 8kV (30A) ESD pulse will be:

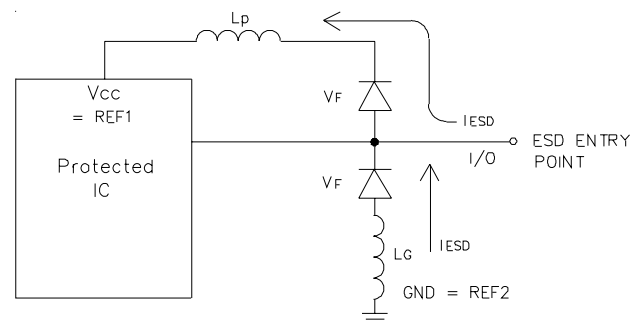
$$V_C = 5V + 30V + (10nH \times 30V/nH) = 335V$$

This does not take into account that the ESD current is directed into the supply rail, potentially damaging any components that are attached to that rail. Also note the high  $V_F$  of the discrete diode. It is not uncommon for the  $V_F$  of discrete diodes to exceed the damage threshold of the protected IC. This is due to the relatively small junction area of typical discrete components. It is also possible that the power dissipation capability of the discrete diode will be exceeded, thus destroying the device.

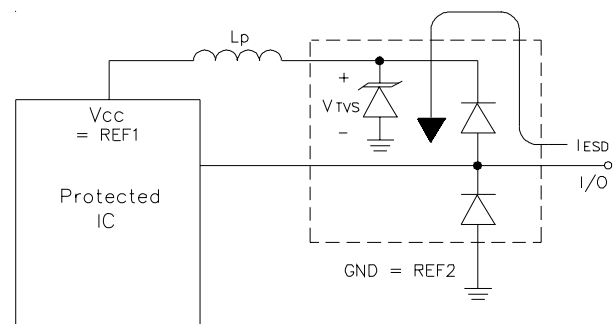
The RailClamp is designed to overcome the inherent disadvantages of using discrete signal diodes for ESD suppression. The RailClamp's integrated TVS diode helps to mitigate the effects of parasitic inductance in the power supply connection. During an ESD event,



**Figure 1 - "Rail-To-Rail" Protection Topology (First Approximation)**



**Figure 2 - The Effects of Parasitic Inductance When Using Discrete Components to Implement Rail-To-Rail Protection**



**Figure 3 - Rail-To-Rail Protection Using RailClamp TVS Arrays**

## PROTECTION PRODUCTS

### Applications Information *(continued)*

the current will be directed through the integrated TVS diode to ground. The total clamping voltage seen by the protected IC due to this path will be:

$$V_C = V_{F(\text{RailClamp})} + V_{\text{TVS}}$$

This is given in the data sheet as the rated clamping voltage of the device. For an SRDA05-4 the typical clamping voltage is <16V at  $I = 30A$ . The diodes internal to the RailClamp are low capacitance, fast switching devices that are rated to handle high transient currents and maintain excellent forward voltage characteristics.

Using the RailClamp does not negate the need for good board layout. All other inductive paths must be considered. The connection between the positive supply and the SRDA and from the ground plane to the SRDA must be kept as short as possible. The path between the SRDA and the protected line must also be minimized. The protected lines should be routed directly to the SRDA. Placement of the SRDA on the PC board is also critical for effective ESD protection. The device should be placed as close as possible to the input connector. The reason for this is twofold. First, inductance resists change in current flow. If a significant inductance exists between the connector and the TVS, the ESD current will be directed elsewhere (lower resistance path) in the system. Second, the effects of radiated emissions and transient coupling can cause upset to other areas of the board even if there is no direct path to the connector. By placing the TVS close to the connector it will divert the ESD current immediately and absorb the ESD energy before it can be coupled into nearby traces.

**(Reference Semtech application note SI99-01 for further information on board layout)**

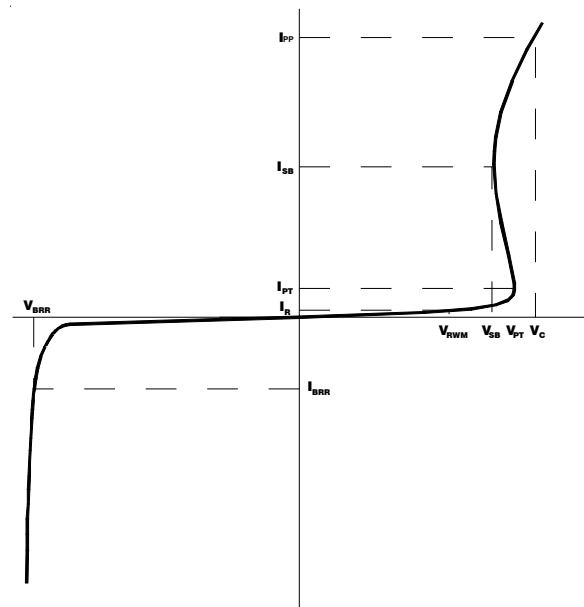
### SRDA3.3-4 EPD TVS Characteristics

The internal TVS of the SRDA3.3-4 is constructed using Semtech's proprietary EPD technology. The structure of the EPD TVS is vastly different from the traditional pn-junction devices that are internal to the SRDA05-4 and SRDA12-4 devices. At voltages below 5V, high leakage current and junction capacitance render conventional avalanche technology impractical for most applications. However, by utilizing the EPD

technology, the SRDA3.3-4 can effectively operate at 3.3V while maintaining excellent electrical characteristics.

The IV characteristic curve of the EPD device is shown in Figure 4. The device represents a high impedance to the circuit up to the working voltage ( $V_{RWM}$ ). During a transient event, the device will begin to conduct as it is biased in the reverse direction. When the punch-through voltage ( $V_{PT}$ ) is exceeded, the device enters a low impedance state, diverting the transient current away from the protected circuit. When the device is conducting current, it will exhibit a slight "snap-back" or negative resistance characteristic due to its structure. This must be considered when connecting the device to a power supply rail. To return to a non-conducting state, the current through the device must fall below the snap-back current (approximately < 50mA) to allow it to travel back through the negative resistance region. If this is a concern, a 10kΩ current limiting resistor can be placed between the supply rail and the positive reference pins (2 and 3) to prevent device latch-up.

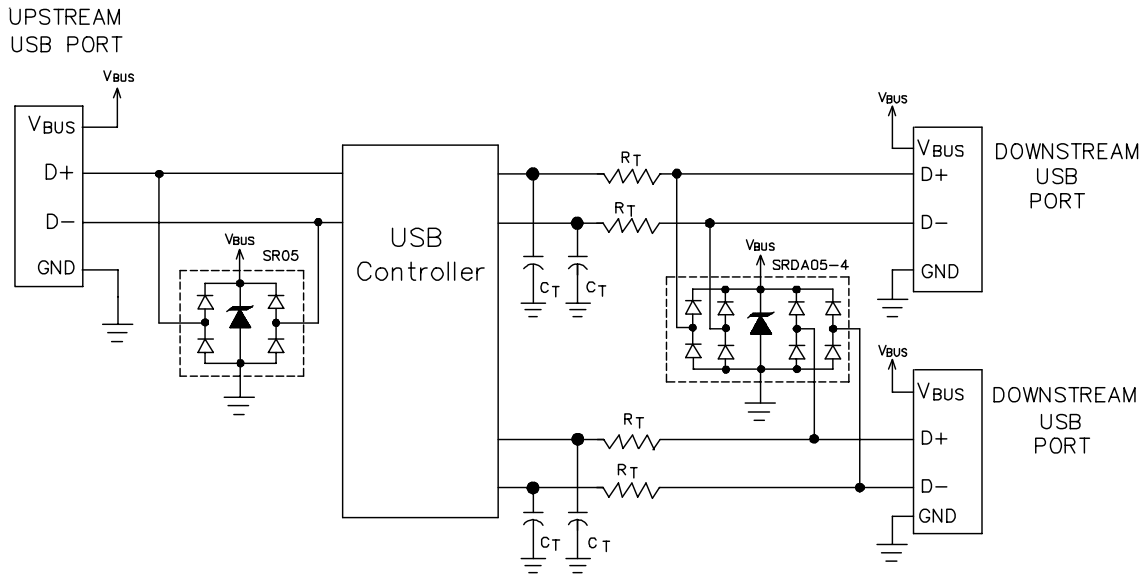
RailClamp is a registered trademark of Semtech corporation



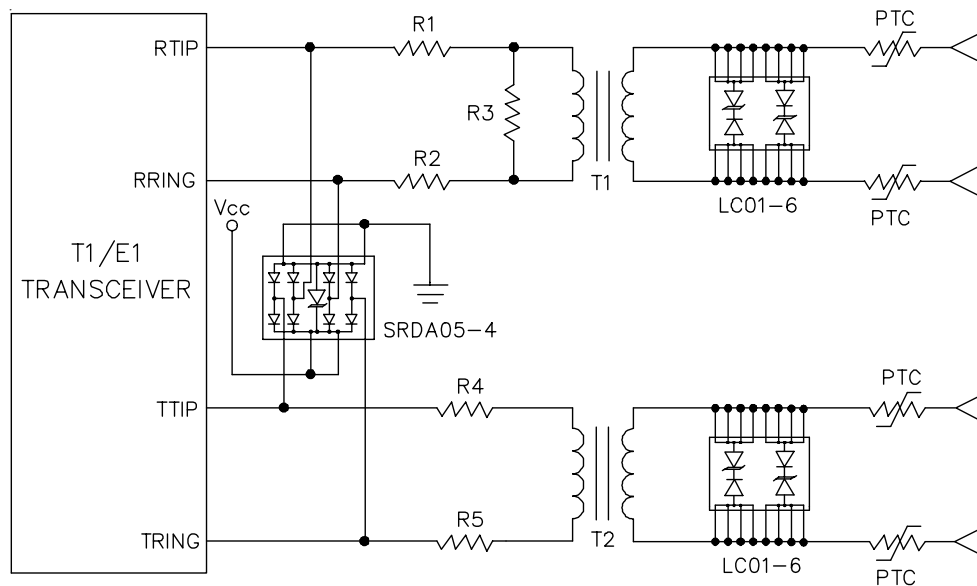
**Figure 4 - EPD TVS IV Characteristic Curve**

PROTECTION PRODUCTS

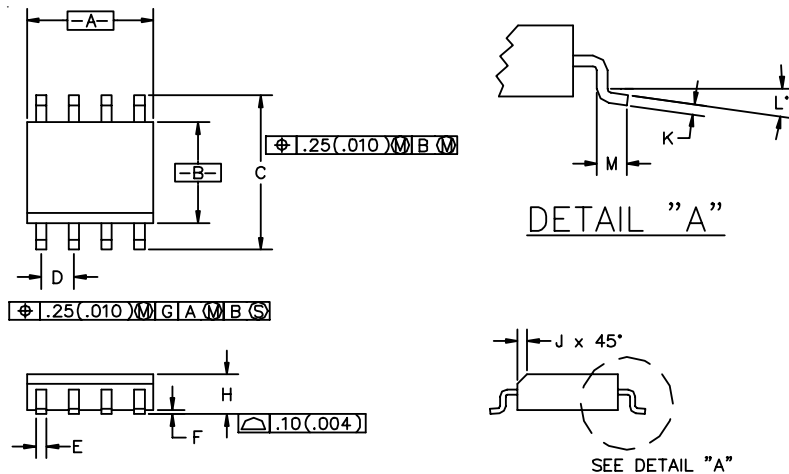
Typical Applications



Universal Serial Bus ESD Protection



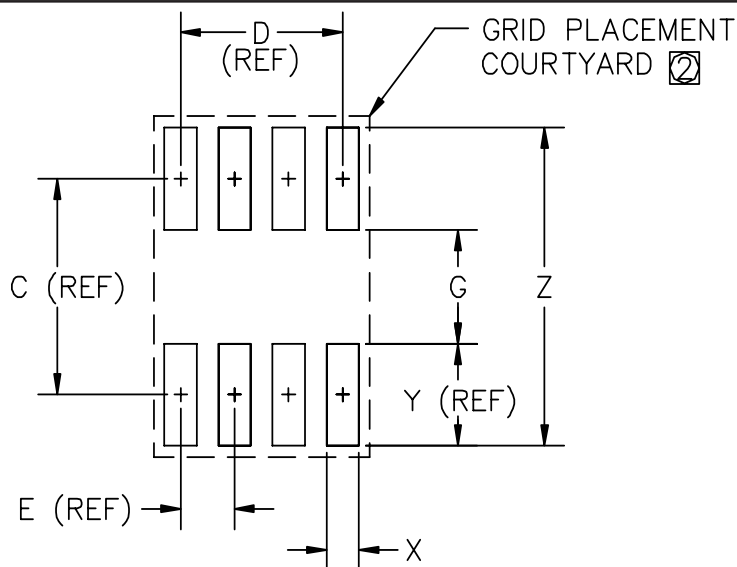
T1/E1 Interface Protection

**PROTECTION PRODUCTS**
**Outline Drawing - S0-8**


DIM <sup>N</sup>	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	.188	.197	4.80	5.00	
B	.149	.158	3.80	4.00	
C	.228	.244	5.80	6.20	
D	.050	BSC	1.27	BSC	
E	.013	.020	0.33	0.51	
F	.004	.010	0.10	0.25	
H	.053	.069	1.35	1.75	
J	.011	.019	0.28	0.48	
K	.007	.010	.19	.25	
L	0°	8°	0°	8°	
M	.016	.050	0.40	1.27	

**Notes:**

(1) Controlling dimension: Inch (unless otherwise specified).

**Land Pattern - S0-8**


DIM <sup>N</sup>	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
C	—	.19	—	5.00	—
D	—	.15	—	3.81	—
E	—	.05	—	1.27	—
G	.10	.11	2.60	2.80	—
X	.02	.03	.60	.80	—
Y	—	.09	—	2.40	—
Z	—	.29	7.20	7.40	—

② GRID PLACEMENT COURTYARD IS 12x16 ELEMENTS (6 mm X 8mm) IN ACCORDANCE WITH THE INTERNATIONAL GRID DETAILED IN IEC PUBLICATION 97.

① CONTROLLING DIMENSION: MILLIMETERS

**PROTECTION PRODUCTS****Ordering Information**

<b>Part Number</b>	<b>Working Voltage</b>	<b>Qty per Reel</b>	<b>Reel Size</b>
SRDA3.3-4.TB	3.3V	500	7 Inch
SRDA3.3-4.TE	3.3V	2500	13 Inch
SRDA05-4.TB	5V	500	7 Inch
SRDA05-4.TE	5V	2500	13 Inch
SRDA12-4.TB	12V	500	7 Inch
SRDA12-4.TE	12V	2500	13 Inch

**Note:**

(1) No suffix indicates tube pack.

**Contact Information**

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Protection Products Division  
200 Flynn Road, Camarillo, CA 93012  
Phone: (805)498-2111 FAX (805)498-3804

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